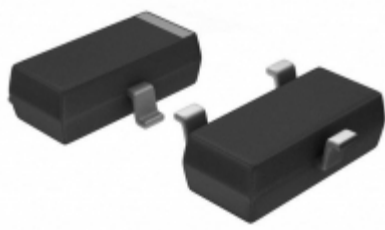






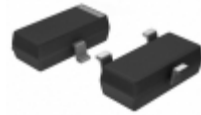


	<b>FJV3111RMTF</b>	
	<b>Hersteller-Teilenummer:</b>	FJV3111RMTF
	<b>Hersteller / Marke:</b>	Fairchild/ON Semiconductor
	<b>Teil der Beschreibung:</b>	TRANS PREBIAS NPN 200MW SOT23-3
	<b>Datenblätter:</b>	<a href="#">1.FJV3111RMTF.pdf</a> <a href="#">2.FJV3111RMTF.pdf</a>
	<b>RoHs Status:</b>	Bleifrei / RoHS-konform
<b>Lagerzustand:</b>	New original, 84000 pcs Stock Available.	
<b>Liefern von:</b>	Hong Kong	
<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS	
Image may be representation. See specs for product details.		

### Spezifikationen

Teilenummer	FJV3111RMTF
Hersteller	Fairchild/ON Semiconductor
Beschreibung	TRANS PREBIAS NPN 200MW SOT23-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-Bipolar
Teilstatus	84000 pcs Stock
Serie	-
Befestigungsart	Surface Mount
Leistung - max	200mW
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Transistor-Typ	NPN - Pre-Biased
Strom - Kollektor (Ic) (max)	100mA
Spannung - Kollektor-Emitter-Durchbruch (max)	40V
VCE Sättigung (Max) @ Ib, Ic	300mV @ 1mA, 10mA
Strom - Collector Cutoff (Max)	100nA (ICBO)
DC Stromgewinn (HFE) (Min) @ Ic, VCE	100 @ 1mA, 5V
Frequenz - Übergang	250MHz
Widerstand - Base (R1) (Ohm)	22k
Widerstand - Emitter-Basis (R2) (Ohm)	-
Verpackung	Tape & Reel (TR)

FJV3111RMTF ist neu im Original, Suche FJV3111RMTF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FJV3111RMTF Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FJV3111RMTF: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>FJV3113RMTF</b> AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p><b>FJV3110RMTF</b> Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p><b>FJV3109RMTF</b> Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p><b>FJV3112RMTF</b> AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>
 <p><b>FJV3114RMTF</b> AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p><b>FJV3109RMTF</b> AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p><b>FJV3111RMTF</b> AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p><b>FJV3113RMTF</b> Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>

### heiße Teile

Mehr

⚙ FJV1845PMTF	➔ FJV1845UMTF	➔ FJV1845UMTF	D FJV3101RLIMTF	➔ FJV3101RMTF
⊣ FJV3101RMTF	⚙ FJV3102RMTF	D FJV3102RMTF	➔ FJV3103RMTF	➔ FJV3103RMTF
⚙ FJV3104RMTF	⊣ FJV3104RMTF	⚙ FJV3105RMTF	➔ FJV3105RMTF	➔ FJV3106RMTF
D FJV3106RMTF	⚙ FJV3107RMTF	⊣ FJV3107RMTF	⚙ FJV3108RMTF	➔ FJV3108RMTF
➔ FJV3109R	➔ FJV3109RMTF	⚙ FJV3109RMTF	⊣ FJV3110RMTF	➔ FJV3110RMTF
➔ FJV3111RMTF	➔ FJV3112RMTF	D FJV3112RMTF	⚙ FJV3113RMTF	⊣ FJV3113RMTF
⚙ FJV3114RMTF	D FJV3114RMTF	➔ FJV3115RMTF	➔ FJV3115RMTF	➔ FJV4101RMTF
⊣ FJV4101RMTF	⚙ FJV4102RLIMTF	➔ FJV4102RMTF	➔ FJV4102RMTF	➔ FJV4103RMTF
⚙ FJV4103RMTF	⊣ FJV4104RMTF	⚙ FJV4104RMTF	D FJV4105RMTF	➔ FJV4105RMTF
➔ FJV4106RMTF	⚙ FJV4106RMTF	⊣ FJV4107RMTF	⚙ FJV4107RMTF	➔ FJV4108RMTF

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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